High-speed switching diodes

Rev. 6 — 24 September 2014

Product data sheet

1. Product profile

1.1 General description

High-speed switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package	Package			Package
	NXP	JEITA	JEDEC		configuration
BAS16	SOT23	-	TO-236AB	single	small
BAS16H	SOD123F	-	-	single	small and flat lead
BAS16J	SOD323F	SC-90	-	single	very small and flat lead
BAS16L	SOD882	-	-	single	leadless ultra small
BAS16T	SOT416	SC-75	-	single	ultra small
BAS16VV	SOT666	-	-	triple isolated	ultra small and flat lead
BAS16VY	SOT363	SC-88	-	triple isolated	very small
BAS16W	SOT323	SC-70	-	single	very small
BAS316	SOD323	SC-76	-	single	very small
BAS516	SOD523	SC-79	-	single	ultra small and flat lead

1.2 Features and benefits

- High switching speed: $t_{rr} \le 4$ ns
- Low leakage current
- Repetitive peak reverse voltage: V_{RRM} ≤ 100 V
- AEC-Q101 qualified

- Low capacitance
- Reverse voltage: V_R ≤ 100 V
- Small SMD plastic packages

1.3 Applications

- High-speed switching
- General-purpose switching



1.4 Quick reference data

Table 2. Quick reference data

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V_R	reverse voltage		-	-	100	V
I _R	reverse current	V _R = 80 V	-	-	0.5	μΑ
t _{rr}	reverse recovery time	$I_F = 10 \text{ mA}; I_R = 10 \text{ mA};$ $R_L = 100 \Omega; I_{R(meas)} = 1 \text{ mA}$	-	-	4	ns

2. Pinning information

Table 3. Pinning

Pin	Description		Simplified outline	Graphic symbol
BAS16; E	BAS16T; BAS16W	,		"
1	anode			_
2	not connected		3	3
3	cathode			1 2 006aaa764
			006aaa144	
BAS16H;	; BAS16J; BAS316; BAS516			
1	cathode	<u>[1]</u>		
2	anode		001aab540	1 2 006aab040
BAS16L				
1	cathode	[1]		
2	anode		Transparent top view	1 2 006aab040
BAS16V\	V; BAS16VY			
1	anode (diode 1)			
2	anode (diode 2)		6 5 4	6 5 4
3	anode (diode 3)			
4	cathode (diode 3)			
5	cathode (diode 2)			
6	cathode (diode 1)		001aab555	1 2 3 006aab106

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Version					
BAS16	TO-236AB	plastic surface-mounted package; 3 leads	SOT23				
BAS16H	-	plastic surface-mounted package; 2 leads	SOD123F				
BAS16J	SC-90	plastic surface-mounted package; 2 leads	SOD323F				
BAS16L	DFN1006-2	leadless ultra small plastic package; 2 terminals; body 1.0 \times 0.6 \times 0.5 mm	SOD882				
BAS16T	SC-75	plastic surface-mounted package; 3 leads	SOT416				
BAS16VV	-	plastic surface-mounted package; 6 leads	SOT666				
BAS16VY	SC-88	plastic surface-mounted package; 6 leads	SOT363				
BAS16W	SC-70	plastic surface-mounted package; 3 leads	SOT323				
BAS316	SC-76	plastic surface-mounted package; 2 leads	SOD323				
BAS516	SC-79	plastic surface-mounted package; 2 leads	SOD523				

4. Marking

Table 5. Marking codes

Type number	Marking code[1]	
BAS16	A6*	
BAS16H	A1	
BAS16J	AR	
BAS16L	S2	
BAS16T	A6	
BAS16VV	53	
BAS16VY	16*	
BAS16W	A6*	
BAS316	A6	
BAS516	6	

^{[1] * =} placeholder for manufacturing site code

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_R	reverse voltage		-	100	V

Table 6. Limiting values ...continued In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
l _F	forward current					
	BAS16		<u>[1]</u>	-	215	mA
	BAS16H BAS16L		[2]	-	215	mA
	BAS16T		<u>[1]</u>	-	155	mA
	BAS16VV BAS16VY		[1][3]	-	200	mA
	BAS16W		<u>[1]</u>	-	175	mA
	BAS16J BAS316 BAS516		[1]	-	250	mA
I _{FRM}	repetitive peak forward current	$t_p \leq 0.5 \text{ ms}; \\ \delta \leq 0.25$		-	500	mA
I _{FSM}	non-repetitive peak forward current	square wave; T _{j(init)} = 25 °C				
		t _p = 1 μs		-	4	Α
		$t_p = 1 \text{ ms}$		-	1	Α
		t _p = 1 s		-	0.5	Α
P _{tot}	total power dissipation					
	BAS16	T _{amb} ≤ 25 °C	<u>[1]</u>	-	250	mW
	BAS16H	T _{amb} ≤ 25 °C	[2]	-	380	mW
			<u>[5]</u>	-	830	mW
	BAS16J	T _{amb} ≤ 25 °C	<u>[5]</u>	-	550	mW
	BAS16L	T _{amb} ≤ 25 °C	[2]	-	250	mW
	BAS16T	T _{sp} ≤ 90 °C	[1][4]	-	170	mW
	BAS16VV	T _{amb} ≤ 25 °C	[1][3]	-	180	mW
	BAS16VY	T _{sp} ≤ 85 °C	[1][3][6]	-	250	mW
	BAS16W	T _{amb} ≤ 25 °C	<u>[1]</u>	-	200	mW
	BAS316	T _{sp} ≤ 90 °C	[1][4]	-	400	mW
	BAS516	T _{sp} ≤ 90 °C	[1][4]	-	500	mW
Per device	•	·			'	,
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	+150	°C
T _{stg}	storage temperature			-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB with 60 μm copper strip line.

^[3] Single diode loaded.

^[4] Soldering point of cathode tab.

^[5] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[6] Soldering points at pins 4, 5 and 6.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air					
	BAS16		<u>[1]</u>	-	-	500	K/W
	BAS16H		[2]	-	-	330	K/W
			[3]	-	-	150	K/W
	BAS16J		[3]	-	-	230	K/W
	BAS16L		[2]	-	-	500	K/W
	BAS16VV		[2][4]	-	-	700	K/W
			[3][4]	-	-	410	K/W
	BAS16W		<u>[1]</u>	-	-	625	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point						
	BAS16			-	-	330	K/W
	BAS16H		<u>[5]</u>	-	-	70	K/W
	BAS16J		<u>[5]</u>	-	-	55	K/W
	BAS16T			-	-	350	K/W
	BAS16VY		[4][6]	-	-	260	K/W
	BAS16W			-	-	300	K/W
	BAS316		<u>[5]</u>	-	-	150	K/W
	BAS516		[5]	-	-	120	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB with 60 μm copper strip line.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [4] Single diode loaded.
- [5] Soldering point of cathode tab.
- [6] Soldering points at pins 4, 5 and 6.

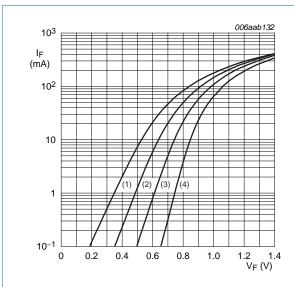
7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

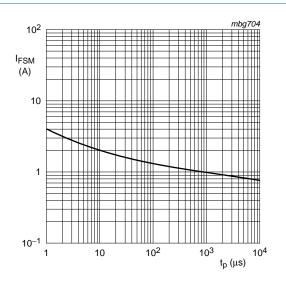
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diode	9						
V _F	forward voltage		<u>[1]</u>				
		I _F = 1 mA		-	-	715	mV
		I _F = 10 mA		-	-	855	mV
		I _F = 50 mA		-	-	1	V
		I _F = 150 mA		-	-	1.25	V
I _R	reverse current	V _R = 25 V		-	-	30	nA
		V _R = 80 V		-	-	0.5	μΑ
		V _R = 25 V; T _j = 150 °C		-	-	30	μΑ
		V _R = 80 V; T _j = 150 °C		-	-	50	μΑ
C _d	diode capacitance	f = 1 MHz; V _R = 0 V					
- u	BAS16; BAS16H; BAS16J; BAS16L; BAS16T; BAS16VV; BAS16VY; BAS16W; BAS316			-	-	1.5	pF
	BAS516			-	-	1	pF
t _{rr}	reverse recovery time	$\begin{split} I_F &= 10 \text{ mA; } I_R = 10 \text{ mA;} \\ R_L &= 100 \ \Omega; \\ I_{R(meas)} &= 1 \text{ mA} \end{split}$		-	-	4	ns
V_{FR}	forward recovery voltage	$I_F = 10 \text{ mA}; t_r = 20 \text{ ns}$		-	-	1.75	V

^[1] Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

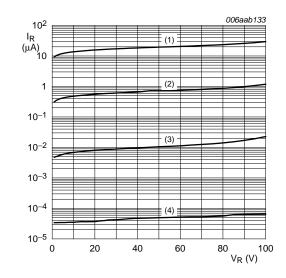
Fig 1. Forward current as a function of forward voltage; typical values



Based on square wave currents.

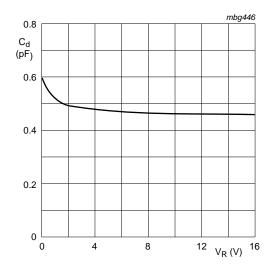
$$T_{j(init)} = 25 \, ^{\circ}C$$

Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

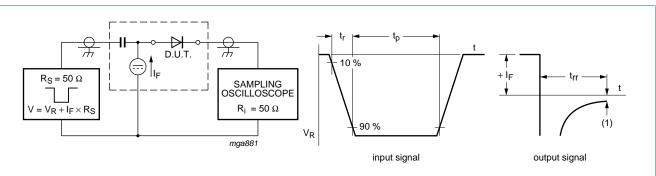
Fig 3. Reverse current as a function of reverse voltage; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}$

Fig 4. Diode capacitance as a function of reverse voltage; typical values

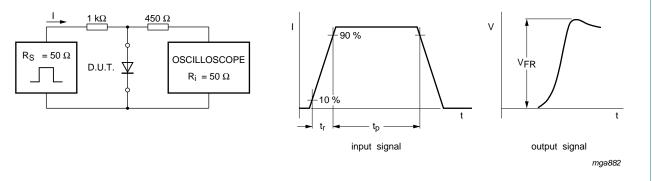
8. Test information



(1) $I_R = 1 \text{ mA}$

Input signal: reverse pulse rise time t_r = 0.6 ns; reverse voltage pulse duration t_p = 100 ns; duty cycle δ = 0.05 Oscilloscope: rise time t_r = 0.35 ns

Fig 5. Reverse recovery time test circuit and waveforms



Input signal: forward pulse rise time $t_r = 20$ ns; forward current pulse duration $t_p \ge 100$ ns; duty cycle $\delta \le 0.005$

Fig 6. Forward recovery voltage test circuit and waveforms

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline

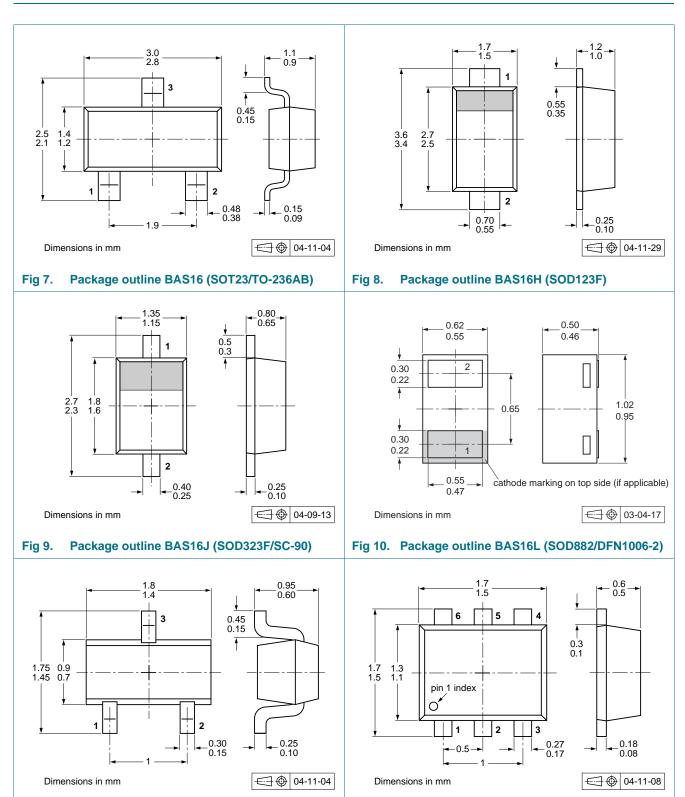
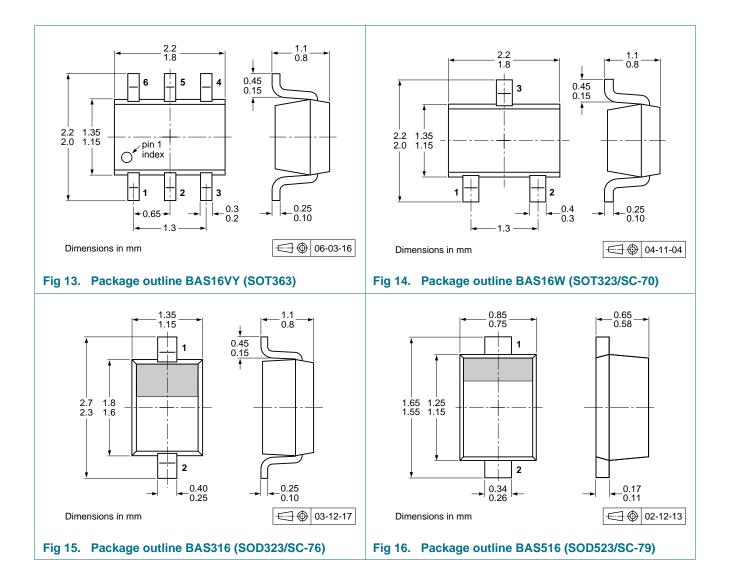
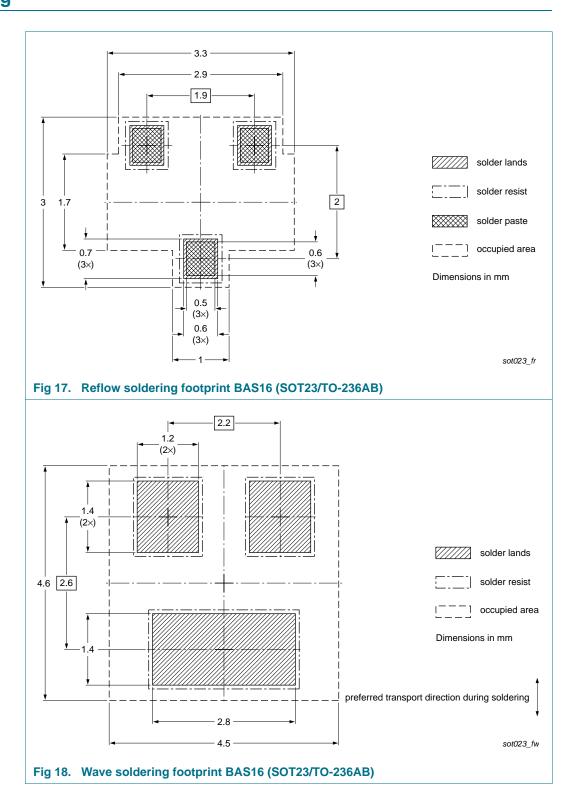


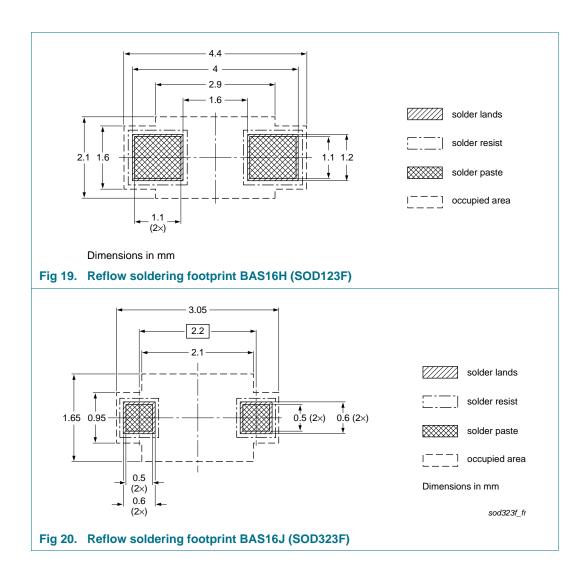
Fig 12. Package outline BAS16VV (SOT666)

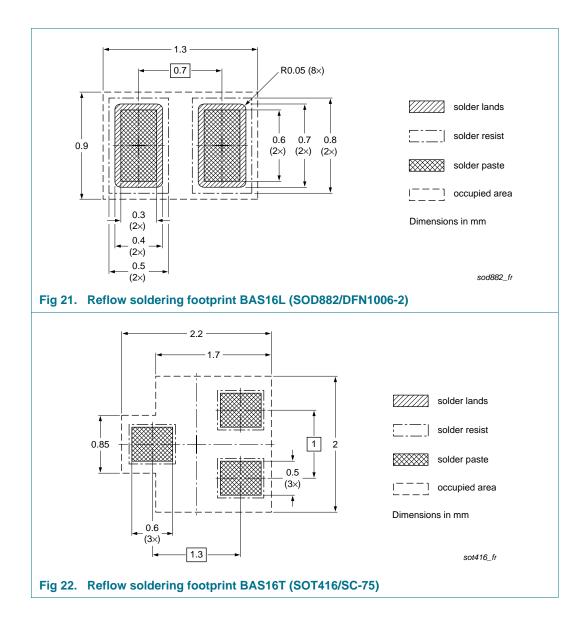
Fig 11. Package outline BAS16T (SOT416/SC-75)

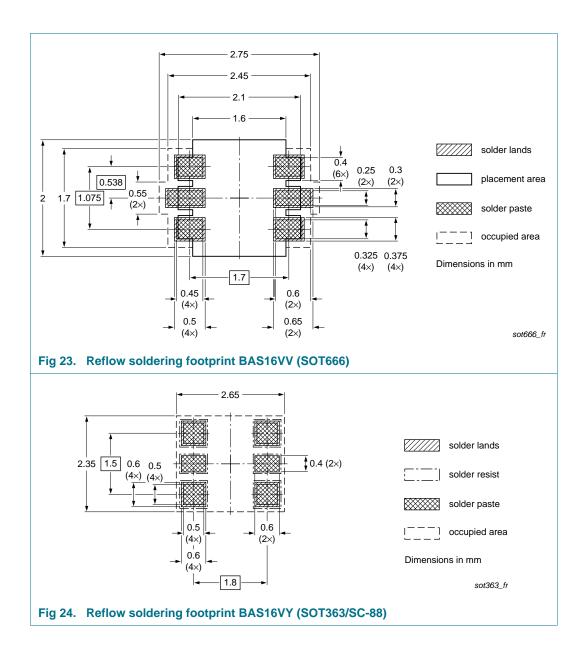


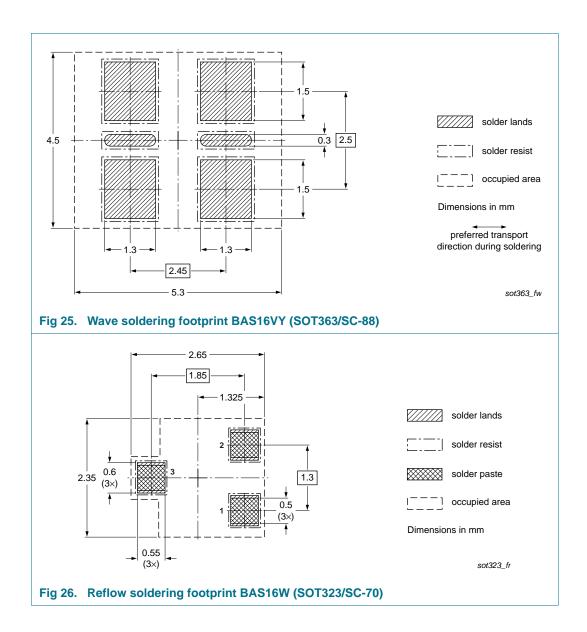
10. Soldering

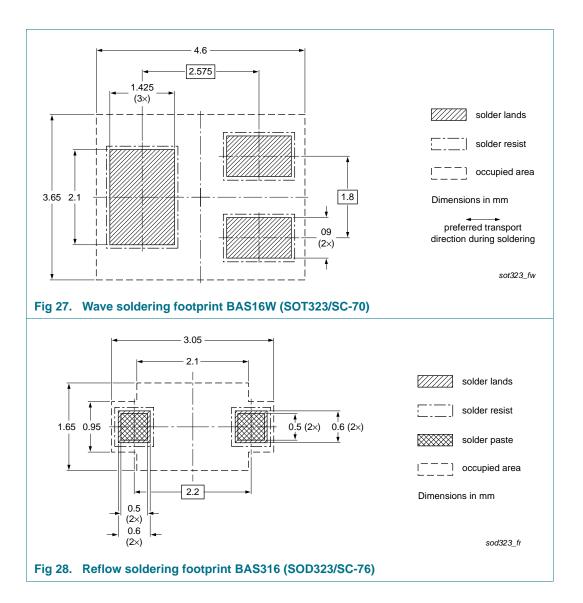


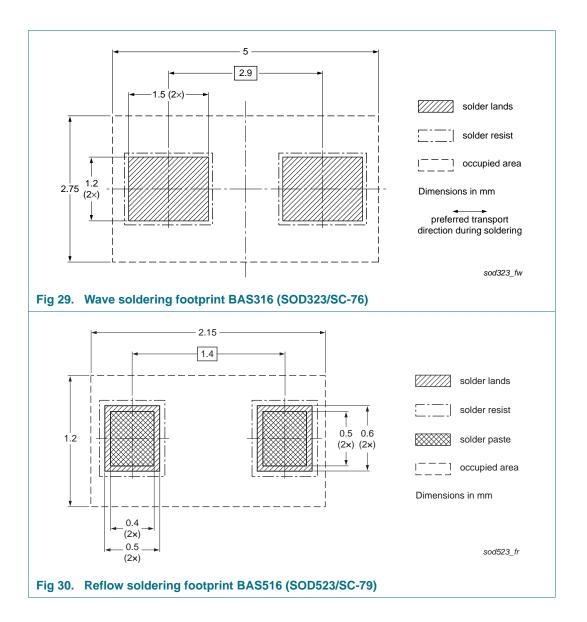












11. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS16_SER_6	20140924	Product data sheet	-	BAS16_SER_5
Modifications:	Section 4 "Ma"Table 6 "Limi"Section 8 "Te"	Features and benefits": update arking": updated ting values": updated est information": updated legal information": updated	ed	
BAS16_SER_5	20080825	Product data sheet	-	BAS16_4 BAS16H_1 BAS16J_1 BAS16L_1 BAS16T_1 BAS16VV_BAS16VY_3 BAS16W_4 BAS316_4 BAS516_1
BAS16_4	20011010	Product specification	-	BAS16_3
BAS16H_1	20050415	Product data sheet	-	-
BAS16J_1	20070308	Product data sheet	-	-
BAS16L_1	20030623	Product specification	-	-
BAS16T_1	19980120	Product specification	-	-
BAS16VV_BAS16VY_3	20070420	Product data sheet	-	BAS16VV_BAS16VY_2
BAS16W_4	19990506	Product specification	-	BAS16W_3
BAS316_4	20040204	Product specification	-	BAS316_3
BAS516_1	19980831	Product specification	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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High-speed switching diodes

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